pFFT in FastMaxwell: A Fast Impedance Extraction Solver for 3D Conductor Structures over Substrate

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Abstract— In this paper we describe the acceleration algorithm implemented in FastMaxwell, a program for wideband electromagnetic extraction of complicated 3D conductor structures over substrate. FastMaxwell is based on the integral domain mixed potential integral equation (MPIE) formulation, with 3-D full-wave substrate dyadic Green’s function kernel. Two dyadic Green’s functions are implemented. The pre-corrected Fast Fourier Transform (pFFT) algorithm is generalized and used to accelerate the translational invariant complex domain dyadic kernel. Computational results are given for a variety of structures to validate the accuracy and efficiency of FastMaxwell. O(NlogN) computational complexity is demonstrated by our results in both time and memory.

I. INTRODUCTION

The integration of RF, analog and digital circuitry on a single integrated-circuit substrate, or system-on-chip (SoC), is associated with many challenges. For instance, substrate noise may lead to altered circuit performance. In addition, conductor skin and proximity effects may impact current return paths in a network of closely-spaced conductors, as well as quality factor in RF inductors. Moreover, the occurrence of radiated electromagnetic interferences (EMI) may transmit disturbances across different SoC systems. In order to avoid all the above problems, electromagnetic simulation tools are needed that can accurately and efficiently extract wide-band full-wave conductor impedances in the presence of semi-conducting substrates.

In the last decade, electromagnetic simulators based on integral formulations have been the subject of extensive research due to the development of fast algorithms i.e. \( O(N \log N) \) for dense linear systems. These algorithms include Fast Multipole Method (FMM) [1]-[3], precorrected-Fast Fourier Transform [4], [5], and SVD compression [6]. Despite of the large variety of acceleration algorithms and efficient codes, there is no single code that is capable of solving 3-D full-wave Maxwell’s equations for arbitrary and very large structures over substrate. For instance, FASTCAP [1], FASTHENRY [2] and ISC3 [6] are based on quasi-static approximations and cannot handle full-wave kernels with substrate effects. FASTIMP [5] solves only the full-wave free space propagation problem and is therefore not suitable for simulating substrate effects. EMX [3] is based on 2.5D formulations with planar metal structures assumed of infinitesimal thickness. This is similar to the formulation in IE3D, though the latter has the ability to model 3-D structures. These approximations are efficient for modeling standard IC technology but not suitable for simulating micromachined structures of complex vertical geometries. Finally, a variety of commercial software based either on Finite Element Methods (FEM) or Finite Difference Time Domain (FDTD) are available and can perform accurate analysis but only on relatively small structures.

In this paper we present a 3D full-wave simulator based on the mixed potential integral equation formulation (MPIE) [7], [8], and accelerated using pFFT. The solver will be released on public domain starting from December 2006 [9]. The simulator is capable of solving Maxwell’s equations for arbitrary 3D multi-port structures over substrate. A variety of acceleration techniques are implemented in the simulator to increase its computational efficiency. The Discrete complex image method (DCIM) [10] is used to approximate the spectral domain Green’s function into closed form and thus avoid the need for time consuming Sommerfeld integrals. The set of integration routines [11] to transform 3D integrations into 1D are also implemented. In this paper we illustrate the use of an alternative dyadic Green function, which can be used to describe the potential of arbitrary oriented dipoles without extra computational effort. The alternative Green’s function has more symmetrical properties, which can be effectively utilized to enforce the generation by our solver of symmetric positive semidefinite matrices for guaranteed passive model order reduction of distributed structures [12]. In addition, we present the complete p-FFT implementation to handle the dyadic, translational invariant dyadic kernel. In the last section of the paper we give a large number of examples demonstrating the accuracy and computational efficiency of our pFFT implementation in FastMaxwell.

II. BACKGROUND

A. MPIE Formulation

As in [7], [8] the following set of integral equation can be used to compute the unknown volumetric current density \( \vec{J}(r) \) and surface charge distribution \( \rho(r) \)

\[
\begin{align}
\vec{J}(r) &= \frac{j \omega}{4 \pi \sigma} \int_V \overrightarrow{G}_v(r, r') \vec{J}(r') dr' = -V \phi(r) \quad (1) \\
-\frac{1}{4 \pi \epsilon} \int_S \overrightarrow{G}_d(r, r') \rho(r') dr' &= \phi(r) \\
\n\n\n\n\quad V \cdot \vec{J}(r) &= 0 \quad (2) \\
\n\n\n\n\hat{n} \cdot \vec{J}(r) &= j \omega \rho(r), \quad (3)
\end{align}
\]

Where \( \overrightarrow{G}_v(r, r') \) and \( \overrightarrow{G}_d(r, r') \) are the dyadic and scalar Green’s functions, respectively. \( V,S \) are the conductors volume and surface area, respectively, \( \phi(r) \) is the scalar potential, \( \epsilon \) is the complex dielectric constant including dielectric losses, \( \mu \) magnetic permeability, \( \omega \) the angular frequency is radians.

B. Formulation Discretization

The conductors volume and surface area are discretized using piecewise constant basis functions into filaments and panels (Fig.1) as in [7], [8], [13] respectively. These are then assembled using Galerkin and mesh analysis [7] into a dense linear system of the form:

\[
V_{m \times 1} = M_{m \times b} \vec{Z}_{b \times b} M_{b \times m}^T \vec{v}_{m \times 1} \quad (5)
\]

where \( b \) is the number of branches of the equivalent circuit, \( m \) is the number of independent meshes, \( M \) is the mesh matrix,
V is the known excitation vector and I is the unknown current vector. Matrix Z is defined as:

\[
Z = \begin{bmatrix}
|R| + joL & \frac{[P]}{j\omega} \\
0 & \frac{[P]}{j\omega}
\end{bmatrix}
\]

The partial matrices \([R], [L]\) and \([P]\) are generated via Galerkin technique for both volumetric and surface current distributions:

\[
R_{ij} = \frac{\ell_i}{\sigma a_i}
\]

\[
L_{ij} = \frac{1}{a_i a_j} \int_{v_i} \int_{v_j} G_A(r,r') \ell_i \cdot \ell_j \, dr' \, dr
\]

\[
P_{ij} = \frac{1}{S_i S_j} \int_{v_i} \int_{v_j} G_0(r,r') \, dr' \, dr
\]

where \(a_i, \ell_i\) are the cross sectional area and directional vector of filament \(i\), respectively and \(S_j\) is the surface area of panel \(i\).

**C. Traditional Dyadic Green’s Function**

The full-wave substrate effects are captured by using the dyadic Green’s function. Different formulations have been previously introduced in literature to satisfy the boundary conditions. In a traditional formulation the horizontal dipole generates horizontal and vertical vector potentials [14]. The scalar potential has two different components corresponding to the horizontal and vertical dipoles.

\[
\overline{\phi}_A(r,r') = \begin{bmatrix} G^{xx} & 0 & 0 \\ 0 & G^{xx} & 0 \\ 0 & 0 & G^{zz} \end{bmatrix}, \phi_0(r,r') = \begin{bmatrix} G^H \\ G^H \\ G^V \end{bmatrix}
\]

The closed form spectral domain components of the Green’s function are summarized in the appendix of [14]. By applying the discrete complex image method the spectral domain components can be transformed into spatial domain counterparts. The spatial domain components can be summarized in the following closed form:

\[
G^{xx}_A(r,r') = g(x-x', y-y', z-z') + \sum_k a_k g(x-x', y-y', z+z' + \beta_k)
\]

\[
G^{yy}_A(r,r') = \frac{\partial}{\partial y} a_k g(x-x', y-y', z+z' + \beta_k)
\]

\[
G^{zz}_A(r,r') = \frac{\partial}{\partial z} a_k g(x-x', y-y', z+z' + \beta_k)
\]

Where \(g(x,y,z)\) is the free space Green’s function, \(a_k, \beta_k\) are complex constants obtained from the DCIM, \(u \in [x,y,z]\) and \(v \in [x,y]\).

D. pFFT

The dense linear system in (5) is typically solved using Krylov subspace iterative methods. It should be noted that a good preconditioner is essential for proper operation of the algorithm. A commonly used preconditioner is \(M_{diag}[Z]M^T\). The solver complexity is dominated by a dense matrix vector product, which can be accelerated using the precorrected Fast Fourier Transform (pFFT) algorithm [4], [5]. The acceleration in pFFT is based on sparsifying the dense matrix vector product by separating it into a direct matrix that accounts for nearby interactions, and an approximated matrix that accounts for the far field weak interactions. The resulting direct interactions constitute a sparse matrix because of the relatively few neighbors of a single element and the matrix vector product can therefore be implemented in \(O(N)\), where \(N\) is the number of unknowns. The weak interactions are approximated via a projection on a regular three-dimensional grid and by making use of the translational invariance of the free space kernel. Interactions on the grid are calculated via fast Fourier transform in \(O(N_g \log N_g)\), where \(N_g\) is the total number of grid points. The final algorithm complexity is \(O(N + N_g \log N_g)\) for the time and \(O(N + N_g)\) for the memory. Typically, the number of grid points is comparable to the number of unknowns.

**III. AN ALTERNATIVE DYADIC GREEN’S FUNCTION**

In spite of its popularity, the dyadic Green’s formulation in section II-C is associated with some disadvantages, including the need for two scalar Green’s functions for the horizontal and vertical dipoles, respectively. This prevents the usage of the formulation for arbitrarily oriented dipoles. In addition, the dyadic kernel in the presence of vertical current is not symmetric, hence it does not allow the generation of symmetric positive semidefinite matrices which would facilitate the passive model order reduction of distributed systems [12].

In order to address these issues we have implemented an alternative formulation for the dyadic kernel [14]. This formulation is associated with a single scalar Green’s function provided the source and observation points are in the same dielectric layer. The existence of a unique scalar potential means that this formulation can be used with dipoles of arbitrary orientations. Furthermore, the dyadic kernel of the alternative formulation is symmetric:

\[
\overline{G}_A(r,r') = \begin{bmatrix} G^{xx} & 0 & 0 \\ 0 & G^{yy} & 0 \\ 0 & 0 & G^{zz} \end{bmatrix}, G_0(r,r') = G^y
\]

The closed form spectral domain components of the Green’s function are summarized in the appendix of [14]. By applying the discrete complex image method the spectral domain components can be transformed into closed form spatial counterparts. The spatial domain components can be summarized in the following closed form:

\[
G^{xx}_A(r,r') = g(x-x', y-y', z-z') + \sum_k a_k g(x-x', y-y', z+z' + \beta_k)
\]

\[
G^{yy}_A(r,r') = \frac{\partial}{\partial y} a_k g(x-x', y-y', z+z' + \beta_k)
\]

\[
G^{zz}_A(r,r') = \frac{\partial}{\partial z} a_k g(x-x', y-y', z+z' + \beta_k)
\]

Where \(g(x,y,z)\) is the free space Green’s function, \(a_k, \beta_k\) are complex constants obtained from the DCIM, and \(v \in [x,y]\).
branch currents are the physical quantity that are associated
formulation is considered in this subsection, while all nec-
the translational invariant traditional Green’s function (section
A. pFFT for Traditional Green’s Function
\[ \int_V \int_{V'} \frac{\partial}{\partial h_1} \frac{\partial}{\partial h_2} g(r,r')dV'dV = \int_V dV \left( \frac{\partial}{\partial h_1} \int_{V'} g(r,r')dV' \right) = \sum_s \int_V dV' \left( \frac{\partial}{\partial h_1} \int_s (s'_2 \cdot S) g(r,r') \right) \]
where \( h_1 \in [x,y] \) and \( h_2 \in [x,y] \). Each summation is performed over the two surfaces perpendicular to the corresponding integration variable. We therefore have transformed the three dimensional integration with the second order kernel into a sum of four two dimensional integrations. These surface integrals can be accelerated using the same integration technique in [11]. The formulation presented in this paper has the major advantage of handling dipoles with arbitrary orientation, provided they are confined to a single dielectric layer. For conductor structure distributed in different layers either formulation A or formulation C in [14] must be used.

IV. pFFT for Full-Wave Dyadic Kernel
A. pFFT for Traditional Green’s Function
In this section we show how the MPMIE formulation with the translational invariant traditional Green’s function (section II-C) can be accelerated using pFFT. Only the traditional formulation is considered in this subsection, while all necessary modifications required for the alternative symmetric formulation are detailed in the next subsection. Equation (5) needs to be modified such that the unknown vector is the branch currents rather than mesh currents. This is because the branch currents are the physical quantities that are associated with the discretization elements and that are projected on the grid.

\[ V_{m \times 1} = M_{m \times b} Z_{b \times b} I_{b \times 1} \]

where \( I_{b \times 1} \) is the vector composed of the currents density vector in the filaments \( \mathbf{I}_f = [I_x, I_y, I_z] \) and the current in the panels \( I_p \).

\[ I_{b \times 1}^T = ( \mathbf{I}_f^T, I_p^T ) \]

Furthermore, equations (5) and (7)- (10) define the branch voltages \( V_{b \times 1} = Z_{b \times b} I_{b \times 1} \):

\[ V_{b \times 1} = \begin{pmatrix} [R] I_f \\ 0 \end{pmatrix} + \begin{pmatrix} \frac{j \omega L_{xx}}{\partial} I_x \\ \frac{j \omega L_{yx}}{\partial} I_y \\ \frac{j \omega L_{yz}}{\partial} I_y \\ \frac{P_{ij}}{\partial} I_p \end{pmatrix} \]

where \( [R] \) is diagonal and therefore the first matrix vector product \( [R] I_f \) does not require acceleration. The second term is composed of six matrix vector products, \( [L_{xx}], [L_{yx}], [L_{yz}], [L_{xy}], [L_{yy}], [L_{yz}] \) and \( [P] I_p \). The elements of the matrices \([L] \) and \([P] \) are:

\[ L_{ij} = \frac{1}{a_{ij}} \int_V \int_{V_j} dr' dr (g(x-x',y-y',z-z')) + \sum_k a_{k} g(x-x',y-y',z+z'+\beta_k) \tilde{r}_{in} \cdot \tilde{t}_{jn} \]  
\[ L_{ij} = \frac{1}{a_{ij}} \int_V \int_{V_j} dr' dr \cdot \sum_k a_{k} \frac{\partial}{\partial y} g(x-x',y-y',z+z'+\beta_k) \tilde{r}_{iv} \cdot \tilde{t}_{jv} \]

\[ P_{ij} = \frac{1}{S_{ij}} \int_S \int_{S_j} dr' dr (g(x-x',y-y',z-z')) + \sum_k a_{k} g(x-x',y-y',z+z'+\beta_k) \]

Each of the six matrix vector products is accelerated independently using pFFT, because of the different nature of the discretization elements and Green function kernel in each product. Without loss of generality only (19) and (20) are treated in this analysis since (21) is identical to (20) up to the dimension of the integration. From (19) and (20) we observe that three different projection matrices are required; for \( g(x), \frac{\partial g(x)}{\partial x}, \) and \( \frac{\partial^2 g(x)}{\partial x^2} \). The first term in (19) is clearly translational invariant and can be handled using traditional pFFT. The second term in (19) and the term in (20), which are a result of the Green’s function associated with the complex images, are translational invariant in \( x, y \) but do change with \( z \). The resulting matrix is therefore two-level Toeplitz and one level Hankel. Therefore, these terms cannot be treated with traditional pFFT. The Hankel portion of the matrix must first be transformed into a Toeplitz matrix using an appropriate permutation, multiplied by the vector using FFT and then re-transformed back using the inverse permutation:

\[ H_x = P^{-1} P[H_x] = P^{-1}[P(H) x] = P^{-1}[T(x)] \]

where \( H \) is a two level Toeplitz and one level Hankel matrix, \( T \) is a three level Toeplitz matrix, \( x \) is the input vector, and \( P = P_3 \) is a permutation matrix defined recursively, such that:

\[ P_{N+1} = \begin{pmatrix} P_N & 0 & 0 \\ 0 & 0 & 0 \\ 0 & 0 & P_N \end{pmatrix} \]

where \( P_1 \) is the anti-diagonal unity matrix with elements \( (P_{1,i,i+1} = 1) \), and \( P_3^{-1} = P_3 \). The size of the matrices \( P_3, P_2, \) and \( P_1 \) depends on the number of grid points in the \( x,y,z \) directions, respectively. The Hankel matrix is generated by traversing the grid in the sequence \( z, x, y \). The proposed permutation has the effect of reversing the order of the \( z \) grid index, which means that the multiplication can be implemented without any extra cost by mapping the \( z \) index as \( k \rightarrow K-k \), where \( k \) is the \( z \) index and \( K \) is the total number of grid points in the direction. We conclude that the vector multiplication with the Hankel matrix can therefore be implemented with exactly the same computational complexity as the Toeplitz matrix, i.e. in \( O(N_b \log N_z) \). After constructing the six matrix vector product the mesh voltages are obtained from the branch current using (16) and (18):

\[ V_{m \times 1} = M_{m \times b} V_{b \times 1} \]

Consequently, a standard Krylov subspace iterative technique can be used to solve the dense linear system in \( O(N_b \log N_z) \).

B. pFFT for the Alternative Green’s Function
In this section we present the pFFT implementation with the alternative Green’s function presented in section III. Equations
Equations (18) - (21) are re-written for the alternative kernel, and hence are also valid for this alternative implementation. Equations (16) and (17) in section IV-A are independent on the kernel, avoiding redundant calculations: the direct and pre-correction matrices fill time is optimized by further increase the computational efficiency of FastMaxwell, is dominated by both the fill time and the solution time. To orientation.

Green's function is its ability to handle dipoles in arbitrary significant cost reduction both in time and memory. However, we should note that the additional interpolation matrices is insignificant and does still three. Fortunately, the computational effort required for the mutual inductance terms can be significantly reduced. However, we should note that the computational effort required for the mutual inductance terms is terminated by 50\(\mu\)m, respectively. A set of 50 vertical square vias connect the thickness 1\(\mu\)m and 4\(\mu\)m and distance to ground 5\(\mu\)m and 10.2. The line is surrounded by two shields as described in Fig.5. All the inductors are identical array of square inductors (Fig.5). All the inductors are identical second example is a single microstrip line terminated by a spiral. The isolation coefficient \(S_{12}\) between one inductor in the corner of the array and all the inductor in the diagonal of the array including the element itself are calculated and compared against IE3D (Fig.6). The small discrepancies are mainly due to the excitation mechanism and the planar approximation in the last example. In Fig.4 FastMaxwell results are compared against IE3D. Very good matching is observed. Array of RF inductors. The third example we use to establish the accuracy of our solver consists of an array of 16 element array of square inductors (Fig.5). All the inductors are identical and are separated by 200\(\mu\)m. Each inductor area is 0.01mm\(^2\). Copper wires are 2\(\mu\)m thick and 15\(\mu\)m wide. The separation distance between each of the 3 turns is 5\(\mu\)m. An underpass is situated 1\(\mu\)m below the inductor to contact the center of the spiral. The isolation coefficient \(S_{12}\) between one inductor in the corner of the array and all the inductor in the diagonal of the array including the element itself are calculated and compared against IE3D (Fig.6). The small discrepancies are mainly due to the excitation mechanism and the planar approximation in IE3D.

V. RESULTS

A. Accuracy Validation

In this section we establish the accuracy of our solver by validating its results in examples small and simple enough, such that they can be solved also by available commercial software. Shorted transmission line. The first example (Fig.2) is a microstrip tub [16] consisting of two quarter wavelength copper microstrip lines embedded in a half space of dielectric constant 4.4 and isolated by a microstrip tub. The lines are 10\(\mu\)m above a ground plane and have dimensions: width=5\(\mu\)m height=4\(\mu\)m length=400\(\mu\)m, and center to center separation 20\(\mu\)m. Three identical parallel shields are used to isolate the lines. Each shield consists of two parallel lines of width 4\(\mu\)m, thickness 1\(\mu\)m and 4\(\mu\)m and distance to ground 5\(\mu\)m and 10\(\mu\)m, respectively. A set of 50 vertical square vias connect the lines and the ground. The signal carrying microstrip lines are terminated by 50\(\Omega\) lumped element resistances for matching. The isolation coefficient \(S_{12}\) is simulated and compared against results obtained from IE3D (Fig.3). Microstrip line. The second example is a single microstrip line terminated by a short circuit and placed in a half space of dielectric constant 10.2. The line is surrounded by two shields as described in the last example. In Fig.4 FastMaxwell results are compared against IE3D. Very good matching is observed. Array of RF inductors. The third example we use to establish the accuracy of our solver consists of an array of 16 element array of square inductors (Fig.5). All the inductors are identical and are separated by 200\(\mu\)m. Each inductor area is 0.01mm\(^2\). Copper wires are 2\(\mu\)m thick and 15\(\mu\)m wide. The separation distance between each of the 3 turns is 5\(\mu\)m. An underpass is situated 1\(\mu\)m below the inductor to contact the center of the spiral. The isolation coefficient \(S_{12}\) between one inductor in the corner of the array and all the inductor in the diagonal of the array including the element itself are calculated and compared against IE3D (Fig.6). The small discrepancies are mainly due to the excitation mechanism and the planar approximation in IE3D.

B. P-FFT Validation

The following examples have been used to demonstrate the computational efficiency of the pFFT implementation:
1 Industry provided three dimensional interconnect structure composed of two parallel microstrip lines surrounded by a set of horizontal wires and connected to the ground plane via six thick vias (Fig. 7).
2 two microstrip lines isolated by a microstrip tub and terminated by 50 ohm lumber resistor.
3 three-turn square RF inductor placed 4.8um above a patterned finite ground plane.
4 Array of 8 inductors on top of semi-conducting substrate
5 Array of 16 inductors in free space
6 Power and ground distribution grid with 400 ports and two metal layers
7 Power and ground distribution grid with 900-ports and of two metal layers.

Note that fullwave analysis is necessary in testcases 4 to 7 since the overall array dimension exceeds one wavelength. All the simulations have been performed on a desktop computer with a Pentium IV microprocessor with 2GHz clock frequency, 256MB of cache, 1GB of RAM, and operating under Redhat Enterprise Linux, kernel 2.4.21-37.EL. The parameters of the pFFT algorithm such as grid size, stencil sizes and iterative algorithm convergence criteria are tuned to obtain accuracy of 5% compared to the exact vector matrix product. If exact results cannot be obtained, then pFFT is repeated with higher accuracy until change in results does not exceed 2%. Table I summarizes the overall time and memory performance of the complete solver. In the last two examples the exact results cannot be obtained and numbers are estimated based on complexity asymptotes. It can be observed that the time computational complexity of FastMaxwell is $O(N \log N)$ and that of memory is $O(N)$, as opposed to $O(N^2)$ and $O(N^2)$ for the exact vector matrix product.

C. Validation of pFFT Optimization

The implementation optimization techniques suggested in section IV-C are validated by simulating the array of identical inductors with different number of inductors and with different discretizations. In Fig. 8 pFFT overall time is decomposed into its two main components, matrix fill time and solution time. Matrix fill time is shown for the full-wave substrate Green’s function with integrations calculated with and without the optimization techniques. It is observed that the matrix fill time dominates for small sized and medium sized problems up to a few tens of thousands of unknowns, because of the complexity of the integrated kernel and the lack of closed form analytical
behaves as $O(N \log N)$. The only way to reduce the solution time is to use a better preconditioner and therefore reduce the number of iterations required for convergence. Analogous conclusions are valid for the memory requirements of small and large examples: in small examples the memory consumed is a function of $N$ and the number of direct neighbors of each element. Asymptotically the number of neighbors is a constant determined by the pFFT parameters and the memory computational complexity grows as $O(N)$.

### VI. CONCLUSION

In this paper we have presented a complete pFFT implementation of a fullwave electromagnetic field solver based on the MPIE formulation with dyadic substrate Green function. The alternative Green function implemented in the code can be used for the MPIE formulation with dyadic substrate Green function. The accuracy and efficiency of FastMaxwell and the implemented acceleration algorithms has been established by a variety of examples as large as 100,000 unknowns. The pFFT computational complexity of $O(N \log N)$ in overall solver time and $O(N)$ in memory usage has been observed from our results.

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**TABLE I**

**COMPARISON OF FULL WAVE OVERALL TIME AND MEMORY REQUIREMENTS FOR BOTH PFFT AND EXACT VECTOR MATRIX PRODUCT SOLVERS ON PENTIUM IV AT 200GHZ AND 1GB OF RAM**

<table>
<thead>
<tr>
<th>Structure</th>
<th>pFFT</th>
<th>Exact Method</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Num. unknowns</td>
<td>Memory in (MB)</td>
</tr>
<tr>
<td>3D interconnect</td>
<td>1232</td>
<td>8.7</td>
</tr>
<tr>
<td>Microstrip Tub</td>
<td>1428</td>
<td>9</td>
</tr>
<tr>
<td>Patterned Ground Plane</td>
<td>3295</td>
<td>18.4</td>
</tr>
<tr>
<td>8 Inductor Substrate</td>
<td>4594</td>
<td>24.7</td>
</tr>
<tr>
<td>16 Inductor Array</td>
<td>25342</td>
<td>119</td>
</tr>
<tr>
<td>2D × 20 Power Grid</td>
<td>43486</td>
<td>150</td>
</tr>
<tr>
<td>3D × 30 Power Grid</td>
<td>99342</td>
<td>423</td>
</tr>
</tbody>
</table>

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**Fig. 8.** Comparison between solution time and matrix fill time with and without implementation optimization. The effect of the implementation optimization is to reduce the average matrix filling time by a factor of 8.

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